

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	206	(gate near substrate near capacitance)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:41
L2	20	(oxide near2 gate near2 substrate near2 capacitance)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:41
L3	15	((dielectric or insulating or insulation or insulator) near2 gate near2 substrate near2 capacitance)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:43
L4	2	((dielectric or insulating or insulation or insulator) near2 gate near substrate near capacitance)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:43
L5	10995795	((dielectric or insulating or insulation or insulator) "10" gate near substrate near capacitance)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:43
L6	172	((dielectric or insulating or insulation or insulator) near10 gate near substrate near capacitance)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:46
L7	11	((dielectric or insulating or insulation or insulator) near10 (gate near substrate near capacitance))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:45
L8	4	((dielectric or insulating or insulation or insulator) near10 (gate near2 substrate near2 capacitance)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:45
L9	17813	(gate adj (dielectric or insulating or insulation or insulation)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:46

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L10	9	(gate adj (dielectric or insulating or insulationg or insulation)).clm. and (gate near2 substrate near2 capacitance).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:47
L11	0	(gate adj (dielectric or insulating or insulationg or insulation)).clm. and (gate near2 substrate near2 capacitance).clm. and ((oxide near nitride) or oxynitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:48
L12	0	(gate adj (dielectric or insulating or insulationg or insulation)).clm. and (gate near2 substrate near2 capacitance).clm. and ((oxide near nitride) or oxynitride or oxy-nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:48
L13	1	(gate adj (oxide or dielectric or insulating or insulationg or insulation)) and (gate near2 substrate near2 capacitance).clm. and ((oxide near nitride) or oxynitride or oxy-nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:48
L14	104	(gate adj (oxide or dielectric or insulating or insulationg or insulation)) and (gate near2 substrate near2 capacitance) and ((oxide near nitride) or oxynitride or oxy-nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:49
L15	4	(gate adj (oxide or dielectric or insulating or insulationg or insulation)) same (gate near2 substrate near2 capacitance) same ((oxide near nitride) or oxynitride or oxy-nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:51
L16	317	(gate adj (oxide or dielectric or insulating or insulationg or insulation)) same (capacitance) same ((oxide near nitride) or oxynitride or oxy-nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:51
L17	20	(gate adj (oxide or dielectric or insulating or insulationg or insulation)) same (capacitance) same ((oxide near nitride) or oxynitride or oxy-nitride) same angstrom	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:51

## EAST Search History

L36	0	2002/00521124	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:58
L37	0	"200200521124"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:59
L38	0	I35 and raajmakers	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:58
L39	2	"20020052124"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/13 08:59